

2.49 GHz Low Phase-Noise Optoelectronic Oscillator using 1.55μm VCSEL for Embedded Systems Applications



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Introduction

We present a 1.55μm single-mode VCSEL based low phase-noise optoelectronic oscillator (OEO) operating at 2.49GHz for aerospace, avionics and embedded system applications. A phase-noise measurement of -107 dBc/Hz at an offset of 10kHz from the carrier is obtained. A 3-dB line-width of 16Hz for this oscillator signal has been measured. A parametric comparison with DFB Laser-based and multi-mode VCSEL-based oscillators is also presented.

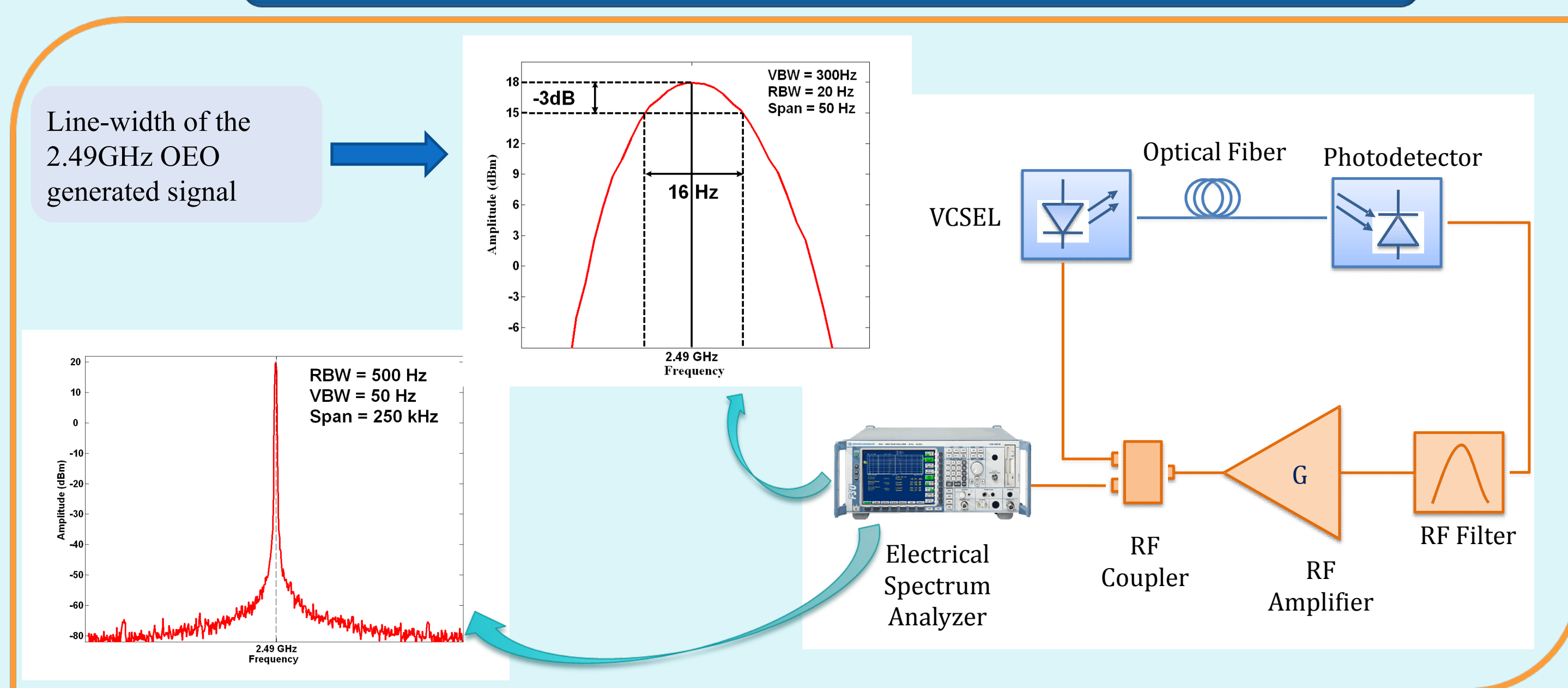
Optoelectronic Loop Oscillator

- High Frequency, Good quality signal.
- No need for a microwave reference.

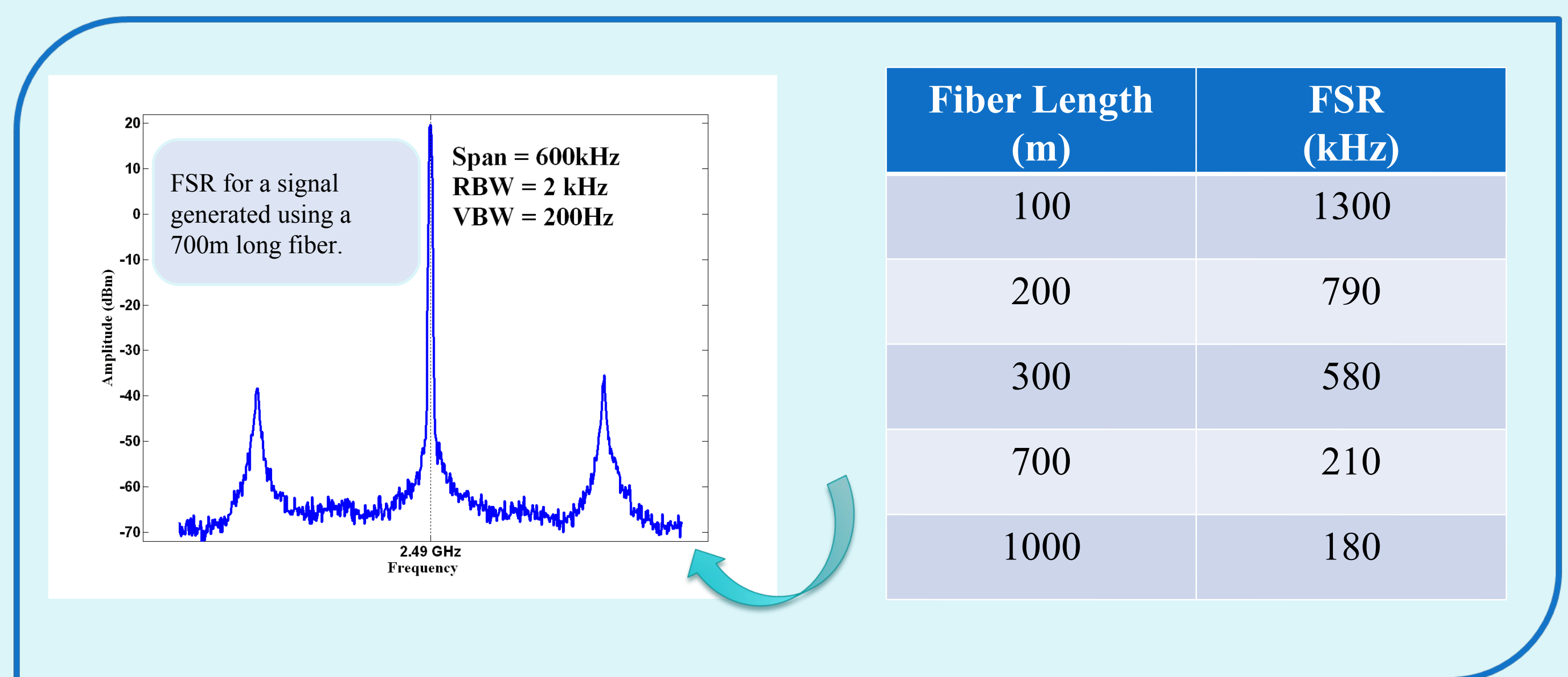
VCSEL Advantages

- Low Power Consumption.
- Light Weight and Compact.
- Low Temperature Dependence.

VCSEL Based Oscillator



Mode-Spacing Variation



Mathematical Representation

The open-loop gain incorporating the VCSEL Transfer Function along with the Amplifier gain can be given as

$$\tilde{G}_{OL} = \tilde{\alpha} \cdot \tilde{G}_{Ampl} \cdot \tilde{\alpha}_o \cdot \tilde{S} \cdot R_{ph} \cdot \tilde{F} \cdot \eta_d \cdot \frac{h\nu}{q} \cdot \frac{1}{R_p(I)|_{I=I_{pd}}} \cdot H_{VCSEL}(\omega)|_{\omega=\omega_o}$$

The numerical expression for the interdependence between the FSR, the fiber length L and the fiber refractive index

$$S_v(f) = \left(1 + \frac{1}{f^2} \left(\frac{f_{osc}}{2Q_c}\right)^2\right) \frac{S_v(f) \cdot G^2_{Ampl}}{P_{osc}} \left(1 + \frac{f_c}{f}\right)$$

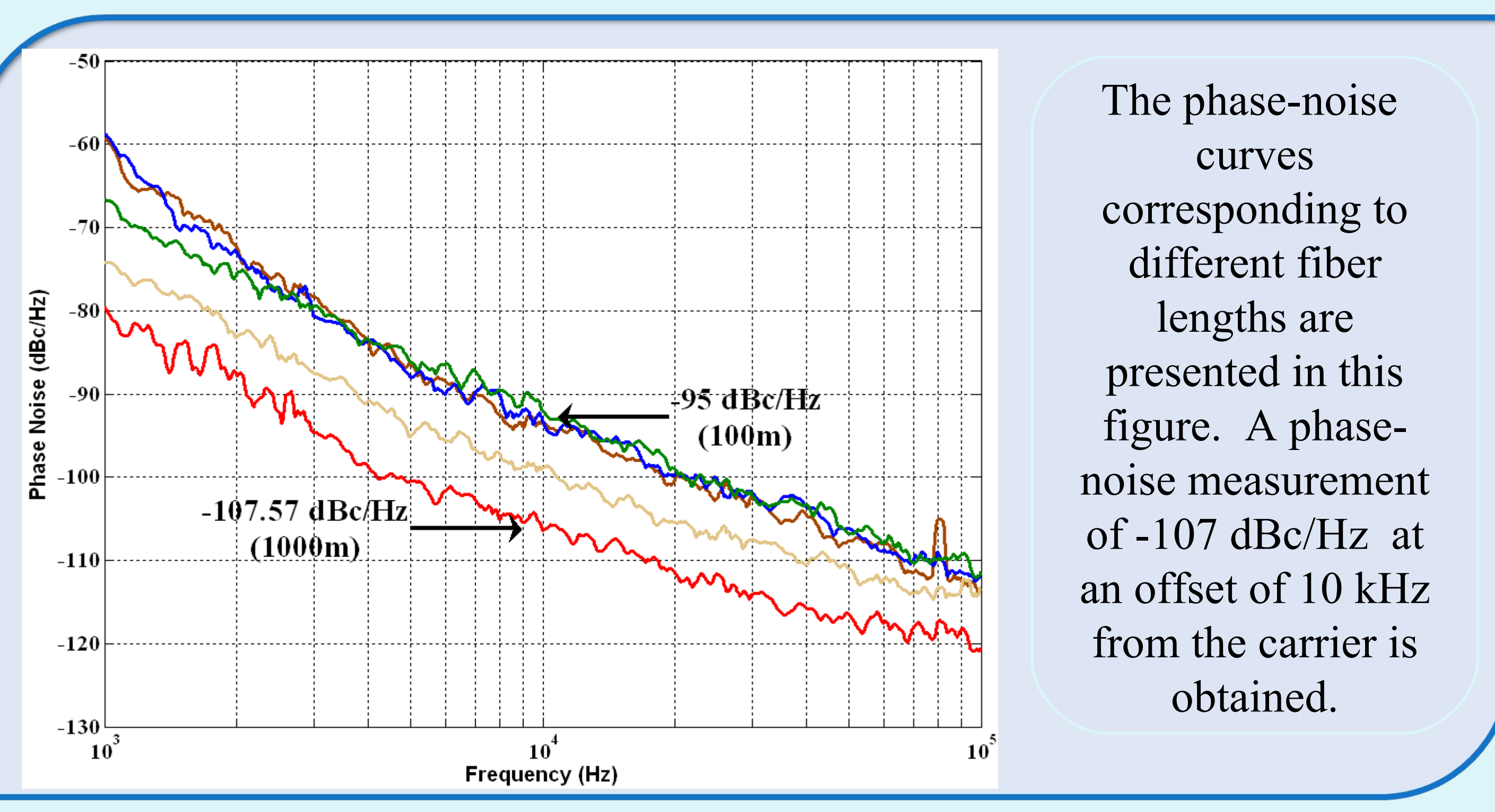
The phase-noise power spectral density in terms of total system noise power spectral density

$$FSR = \frac{1}{\tau_p + \frac{\eta_p \cdot L}{c}}$$

Comparison of OEOs

Oscillator	Fiber Length (m)	I _{bias} (mA)	Laser RIN (dB/Hz)	FSR (MHz)	P _{osc} (dBm)	Phase-Noise @ 10kHz (dBc/Hz)
VBO 850 nm MM 2,49 GHz	120	12.5	-130	1,1	16	-100
VBO 1560 nm SM 2,49 GHz	1000	6	-135	0,180	15,6	-107.57
DBO 1560 nm SM 900 MHz	100	50	-138	1,3	10	-108

Phase-Noise Evolution



Conclusion

The advantages of using 1.55μm single-mode VCSELs to generate high spectral purity signals are their relative insensitivity to temperature variations, their compactness and their very low operation currents. The usage of a single-mode VCSEL guarantees a priori a more spectrally pure system as compared to multi-mode VBOs. The employment of single-mode 1.55μm VCSELs combines the advantages of single-mode 1.55μm DFB-lasers and VCSELs while at the same time eliminating the inconveniences of high power consumption and temperature related output fluctuations.

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 [2]X. S. Yao and L. Maleki, "Optoelectronic Oscillator for Photonic Systems", IEEE Journal of Quantum Electronics, Vol. 32, No. 7, July 1996.
 [3]M. Varón Durán, A. Le Kerneec and J.C. Mollier, "Opto-Microwave Source Using a Harmonic Frequency Generator Driven by a VCSEL-Based Ring Oscillator", Proceedings of the European Microwave Association, Vol.3, Issue 3, pp. 248-253, September 2007.